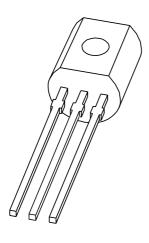
DISCRETE SEMICONDUCTORS

DATA SHEET



BC516PNP Darlington transistor

Product specification Supersedes data of 1999 Apr 23 2004 Nov 05





PNP Darlington transistor

BC516

FEATURES

- High current (max. 500 mA)
- Low voltage (max. 30 V)
- Very high DC current gain (min. 30000).

APPLICATIONS

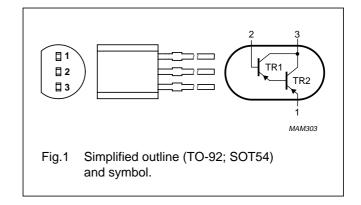
· Where very high amplification is required.

DESCRIPTION

PNP Darlington transistor in a TO-92; SOT54 plastic package. NPN complement: BC517.

PINNING

PIN	DESCRIPTION
1	emitter
2	base
3	collector



ORDERING INFORMATION

TYPE NUMBER	PACKAGE					
TTPE NOWIDER	NAME DESCRIPTION VERSION					
BC516	SC-43A	plastic single-ended (through hole) package; 3 leads	SOT54			

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage (open emitter)	open emitter	_	-40	V
V _{CES}	collector-emitter voltage	V _{BE} = 0 V	_	-30	V
V _{EBO}	emitter-base voltage	open collector	_	-10	V
I _C	collector current (DC)		_	-500	mA
I _{CM}	peak collector current		_	-800	mA
I _B	base current (DC)		_	-100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	_	500	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T _{amb}	ambient temperature		-65	+150	°C

Note

1. Transistor mounted on an FR4 printed-circuit board.

Philips Semiconductors Product specification

PNP Darlington transistor

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THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	note 1	250	K/W

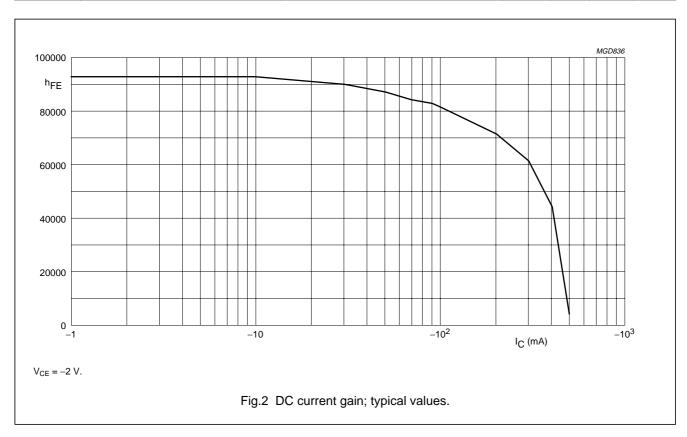
Note

1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	PARAMETER CONDITIONS			MAX.	UNIT
I _{CBO}	collector-base cut-off current	$V_{CB} = -30 \text{ V}; I_E = 0 \text{ A}$	_	_	-100	nA
I _{EBO}	emitter-base cut-off current	$V_{EB} = -10 \text{ V}; I_C = 0 \text{ A}$	_	_	-100	nA
h _{FE}	DC current gain	$I_C = -20$ mA; $V_{CE} = -2$ V; see Fig.2	30000	_	_	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -100 \text{ mA}; I_B = -0.1 \text{ mA}$	_	_	-1	V
V _{BEsat}	base-emitter saturation voltage	$I_C = -100 \text{ mA}; I_B = -0.1 \text{ mA}$	_	_	-1.5	V
V_{BEon}	base-emitter on-state voltage	$V_{CE} = -5 \text{ V; } I_{C} = -10 \text{ mA}$	_	_	-1.4	٧
f _T	transition frequency	$V_{CE} = -5 \text{ V}; I_{C} = -30 \text{ mA}; f = 100 \text{ MHz}$	_	220	_	MHz



Philips Semiconductors Product specification

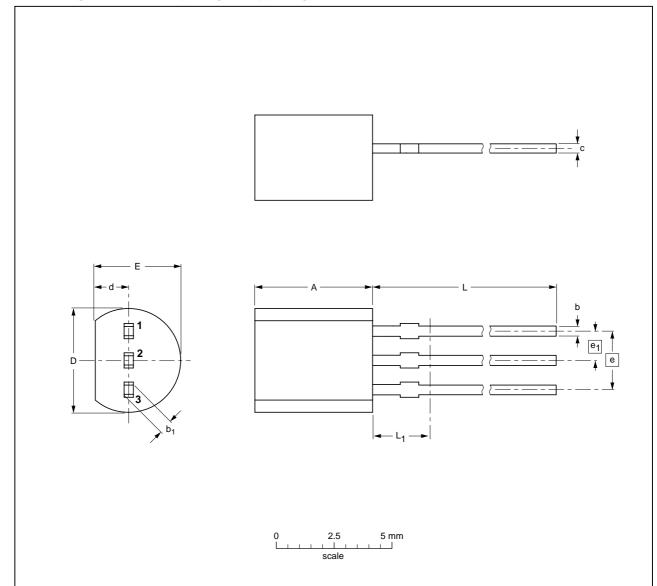
PNP Darlington transistor

BC516

PACKAGE OUTLINE

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



DIMENSIONS (mm are the original dimensions)

UNIT	A	b	b ₁	С	D	d	E	е	e ₁	L	L ₁ ⁽¹⁾ max.
mm	5.2 5.0	0.48 0.40	0.66 0.55	0.45 0.38	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5

Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	VERSION IEC		JEITA		PROJECTION	ISSUE DATE	
SOT54		TO-92	SC-43A			97-02-28 04-06-28	

Philips Semiconductors Product specification

PNP Darlington transistor

BC516

DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS(2)(3)	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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Notes

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